



## APPLICATION DATA SHEET

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<b>Title of Invention</b>	BIPOLAR JUNCTION TRANSISTOR AND FABRICATING METHOD		
Application Type : regular, utility Attorney Docket Number : NAUP0486USA3			
Correspondence address: Customer Number: 027765 			
Continuing Data: This is a Continuation of US application number 10/064,051, filed 2002-06-05 , now PENDING.			
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